

## **IXTK80N25 Datasheet**



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DiGi Electronics Part Number IXTK80N25-DG

Manufacturer IXYS

Manufacturer Product Number IXTK80N25

Description MOSFET N-CH 250V 80A TO264

Detailed Description N-Channel 250 V 80A (Tc) 540W (Tc) Through Hole

TO-264 (IXTK)



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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXTK80N25	IXYS
Series:	Product Status:
MegaMOS™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
250 V	80A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	33mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4V @ 250μA	240 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	6000 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	540W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-264 (IXTK)	TO-264-3, TO-264AA
Base Product Number:	
IXTK80	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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